



PSMN3R3-60PL

N-channel 60 V, 3.4 mΩ logic level MOSFET in SOT78

7 February 2013

Product data sheet

1. General description

Logic level N-channel MOSFET in SOT78 using TrenchMOS technology. Product design and manufacture has been optimized for use in battery operated power tools.

2. Features and benefits

- High efficiency due to low switching & conduction losses
- Robust construction for demanding applications
- Logic level gate

3. Applications

- Battery-powered tools
- Load switching
- Motor control
- Uninterruptible power supplies

4. Quick reference data

Table 1. Quick reference data

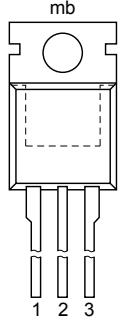
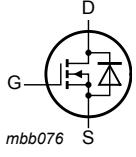
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25 \text{ }^\circ\text{C}; T_j \leq 175 \text{ }^\circ\text{C}$		-	-	60	V
I_D	drain current	$V_{GS} = 10 \text{ V}; T_{mb} = 25 \text{ }^\circ\text{C};$ Fig. 1	[1]	-	-	130	A
P_{tot}	total power dissipation	$T_{mb} = 25 \text{ }^\circ\text{C};$ Fig. 2		-	-	293	W
Static characteristics							
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 11		-	2.7	3.4	$\text{m}\Omega$
Dynamic characteristics							
$Q_{G(tot)}$	total gate charge	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; V_{DS} = 48 \text{ V};$ Fig. 13; Fig. 14		-	175	-	nC
Q_{GD}	gate-drain charge			-	31	-	nC
Avalanche ruggedness							
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 130 \text{ A}; V_{sup} \leq 60 \text{ V}; R_{GS} = 50 \Omega;$ $V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ }^\circ\text{C};$ unclamped; Fig. 3		-	-	372	mJ

[1] Continuous current is limited by package.

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain		
3	S	source	 TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering information

Type number	Package			Version
	Name	Description	Version	
PSMN3R3-60PL	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB		SOT78

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN3R3-60PL	PSMN3R3-60PL

8. Limiting values

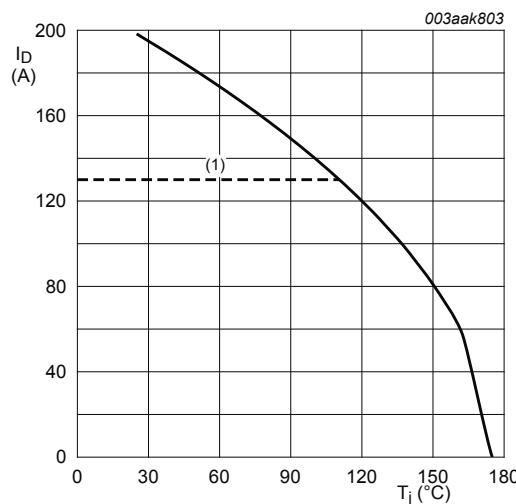
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$		-	60	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20\text{ k}\Omega$		-	60	V
V_{GS}	gate-source voltage			-20	20	V
I_D	drain current	$T_{mb} = 25^\circ\text{C}$; $V_{GS} = 10\text{ V}$; Fig. 1	[1]	-	130	A
		$T_{mb} = 100^\circ\text{C}$; $V_{GS} = 10\text{ V}$; Fig. 1	[1]	-	130	A
I_{DM}	peak drain current	$T_{mb} = 25^\circ\text{C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; Fig. 4		-	793	A

Symbol	Parameter	Conditions	Min	Max	Unit
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; Fig. 2	-	293	W
T_{stg}	storage temperature		-55	175	°C
T_j	junction temperature		-55	175	°C
Source-drain diode					
I_S	source current	$T_{mb} = 25^\circ\text{C}$	[1]	-	130 A
I_{SM}	peak source current	pulsed; $t_p \leq 10 \mu\text{s}$; $T_{mb} = 25^\circ\text{C}$	-	793	A
Avalanche ruggedness					
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 130 \text{ A}$; $V_{sup} \leq 60 \text{ V}$; $R_{GS} = 50 \Omega$; $V_{GS} = 10 \text{ V}$; $T_{j(\text{init})} = 25^\circ\text{C}$; unclamped; Fig. 3	-	372	mJ

[1] Continuous current is limited by package.



(1) Capped at 130A due to package

Fig. 1. Continuous drain current as a function of mounting base temperature

$V_{GS} \geq 10 \text{ V}$

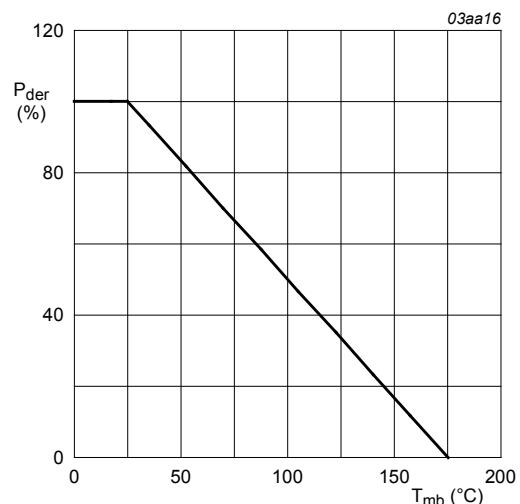


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot}(25^\circ\text{C})} \times 100 \%$$

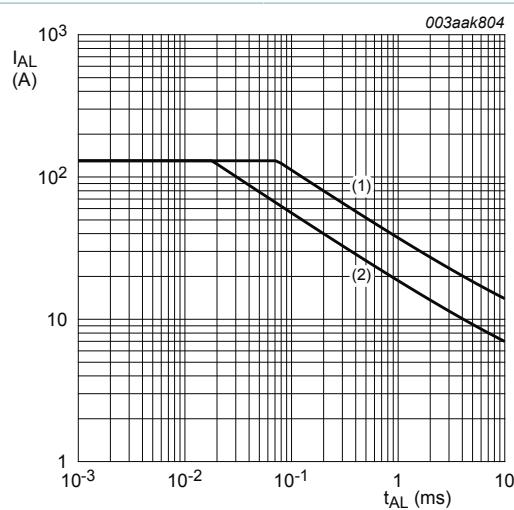


Fig. 3. Avalanche rating; avalanche current as a function of avalanche time

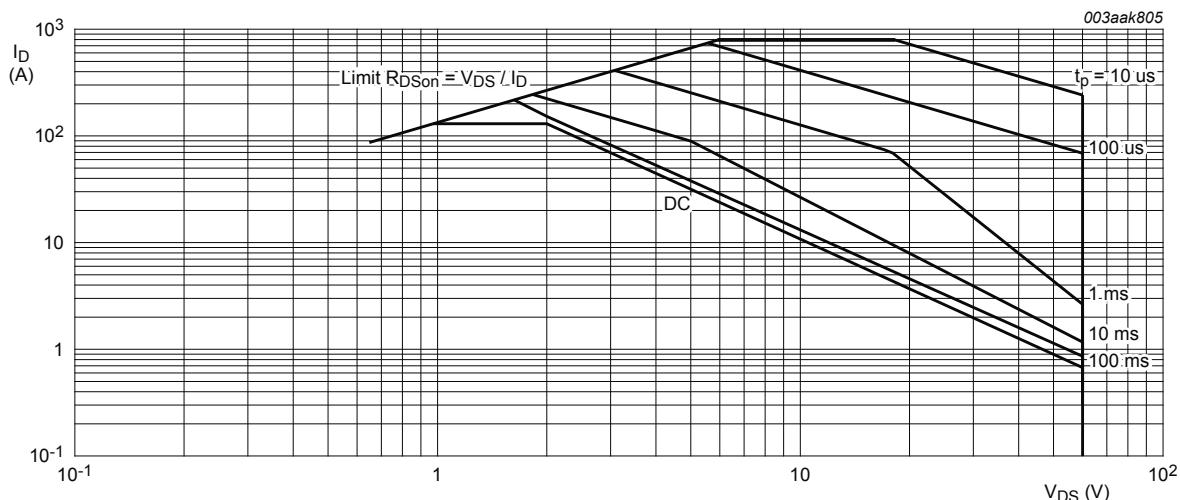
(1) $T_j \text{ (init)} = 25^\circ\text{C}$; (2) $T_j \text{ (init)} = 100^\circ\text{C}$ 

Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^\circ\text{C}$; I_{DM} is a single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	0.4	0.51	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in still air		-	60	-	K/W

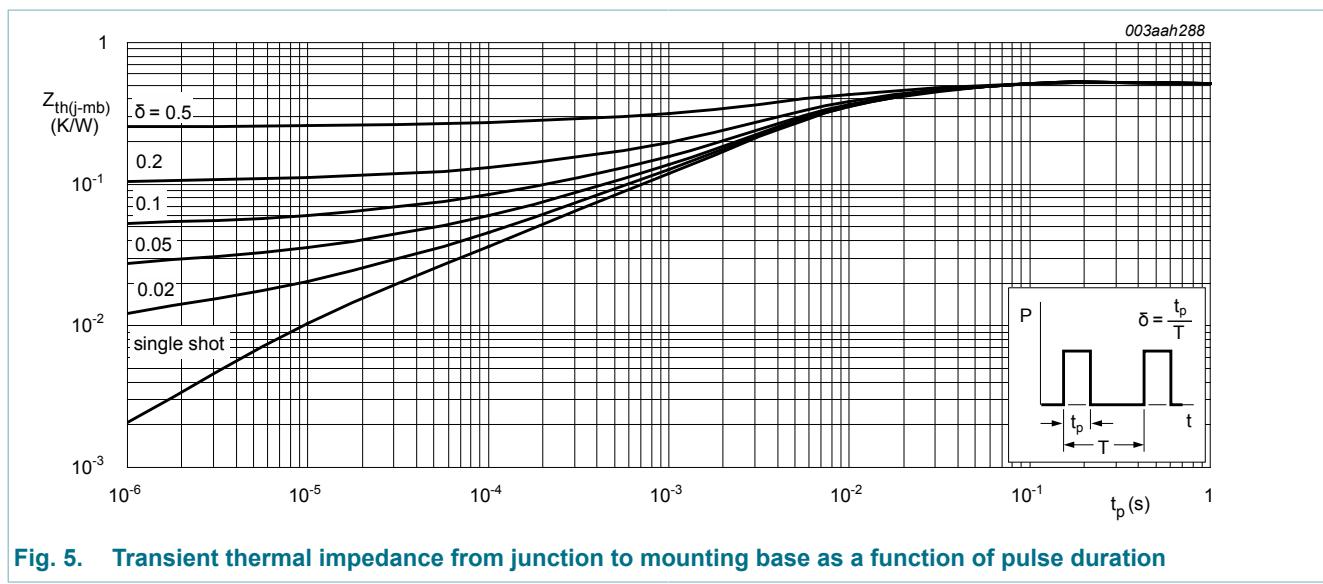


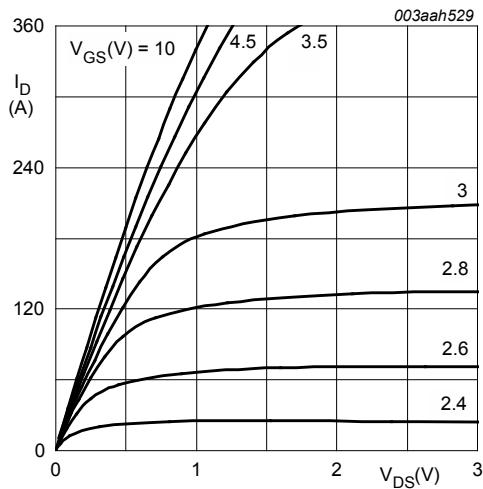
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu\text{A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$		60	-	-	V
		$I_D = 250 \mu\text{A}$; $V_{GS} = 0 \text{ V}$; $T_j = -55 \text{ }^\circ\text{C}$		54	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}$; $V_{DS} = V_{GS}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 9 ; Fig. 10		1.4	1.7	2.1	V
		$I_D = 1 \text{ mA}$; $V_{DS} = V_{GS}$; $T_j = -55 \text{ }^\circ\text{C}$; Fig. 9		-	-	2.45	V
		$I_D = 1 \text{ mA}$; $V_{DS} = V_{GS}$; $T_j = 175 \text{ }^\circ\text{C}$; Fig. 9		0.5	-	-	V
I_{DSS}	drain leakage current	$V_{DS} = 60 \text{ V}$; $V_{GS} = 0 \text{ V}$; $T_j = 175 \text{ }^\circ\text{C}$		-	-	500	μA
		$V_{DS} = 60 \text{ V}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$		-	0.09	1	μA
I_{GSS}	gate leakage current	$V_{GS} = 16 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$		-	2	100	nA
		$V_{GS} = -16 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$		-	2	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}$; $I_D = 25 \text{ A}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 11		-	3	3.8	$\text{m}\Omega$
		$V_{GS} = 10 \text{ V}$; $I_D = 25 \text{ A}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 11		-	2.7	3.4	$\text{m}\Omega$
		$V_{GS} = 10 \text{ V}$; $I_D = 25 \text{ A}$; $T_j = 175 \text{ }^\circ\text{C}$; Fig. 12 ; Fig. 11		-	-	7.5	$\text{m}\Omega$
R_G	gate resistance	$f = 1 \text{ MHz}$		0.5	1	2	Ω

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Dynamic characteristics							
$Q_{G(\text{tot})}$	total gate charge	$I_D = 25 \text{ A}$; $V_{DS} = 48 \text{ V}$; $V_{GS} = 5 \text{ V}$; Fig. 13 ; Fig. 14		-	95	-	nC
Q_{GS}	gate-source charge	$I_D = 25 \text{ A}$; $V_{DS} = 48 \text{ V}$; $V_{GS} = 10 \text{ V}$; Fig. 13 ; Fig. 14		-	175	-	nC
Q_{GD}	gate-drain charge			-	20	-	nC
C_{iss}	input capacitance	$V_{GS} = 0 \text{ V}$; $V_{DS} = 25 \text{ V}$; $f = 1 \text{ MHz}$;		-	10115	-	pF
C_{oss}	output capacitance	$T_j = 25 \text{ }^\circ\text{C}$; Fig. 15		-	822	-	pF
C_{rss}	reverse transfer capacitance			-	427	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 45 \text{ V}$; $R_L = 1.8 \Omega$; $V_{GS} = 5 \text{ V}$;		-	54.2	-	ns
t_r	rise time	$R_{G(\text{ext})} = 5 \Omega$		-	100	-	ns
$t_{d(off)}$	turn-off delay time			-	158	-	ns
t_f	fall time			-	109	-	ns
Source-drain diode							
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 16		-	0.78	1.2	V
t_{rr}	reverse recovery time	$I_S = 20 \text{ A}$; $dI_S/dt = -100 \text{ A}/\mu\text{s}$; $V_{GS} = 0 \text{ V}$;		-	43	-	ns
Q_r	recovered charge	$V_{DS} = 25 \text{ V}$		-	67	-	nC



$T_j = 25 \text{ }^\circ\text{C}$; $t_p = 300 \mu\text{s}$

Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

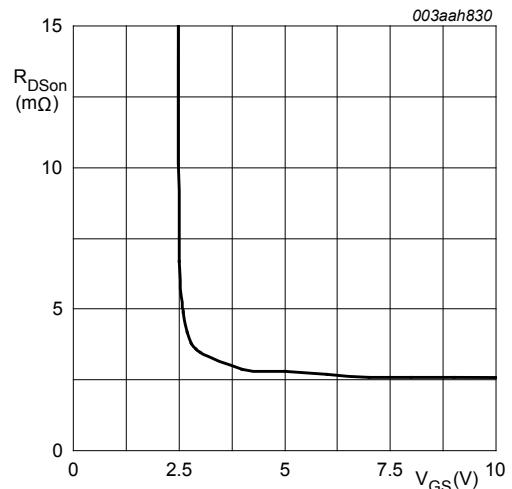


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25 \text{ }^\circ\text{C}$; $I_D = 25 \text{ A}$

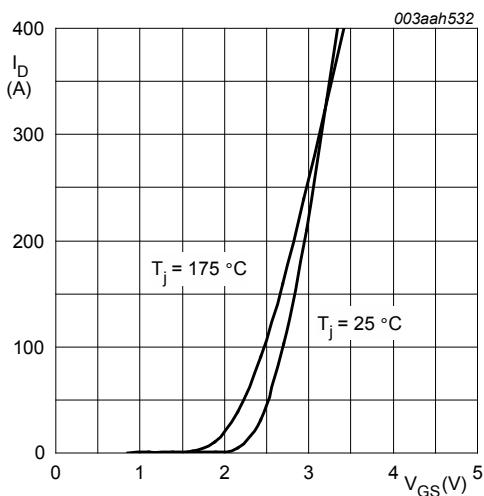


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10V$

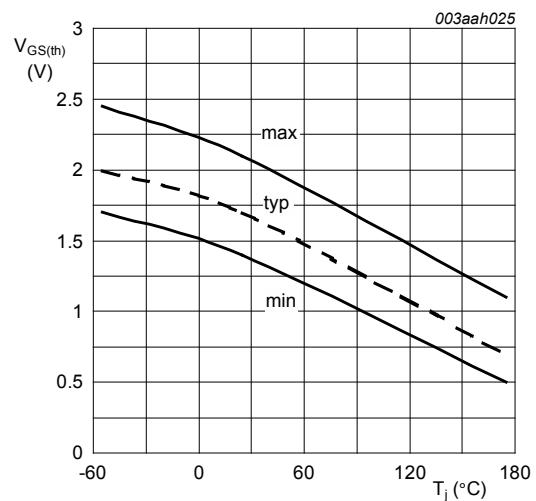


Fig. 9. Gate-source threshold voltage as a function of junction temperature

$I_D = 1$ mA; $V_{DS} = V_{GS}$

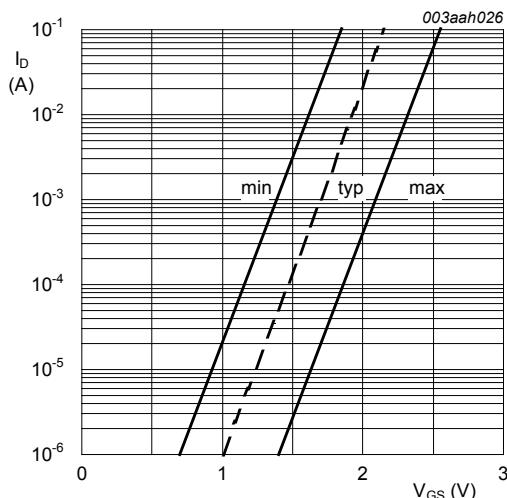


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25$ °C; $V_{DS} = 5V$

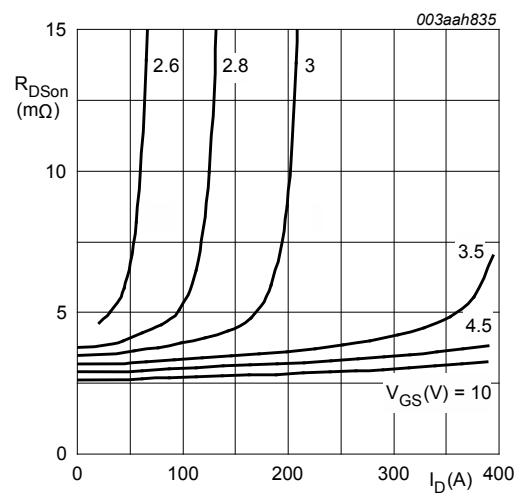


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25$ °C; $t_p = 300$ μs

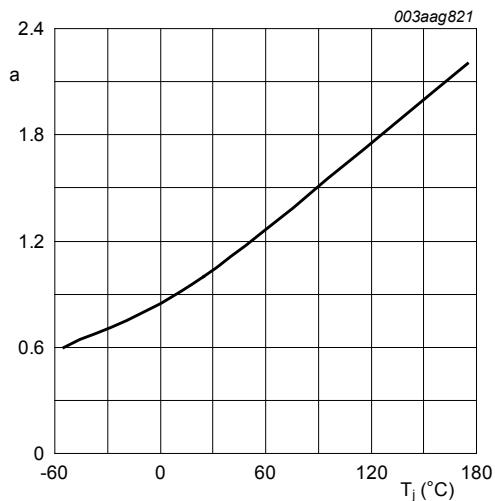


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon(25\text{ }^{\circ}\text{C})}}$$

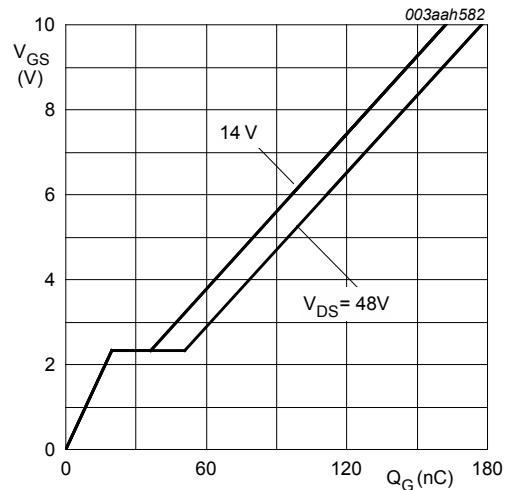


Fig. 14. Gate-source voltage as a function of gate charge; typical values

$T_j = 25\text{ }^{\circ}\text{C}; I_D = 25\text{ A}$

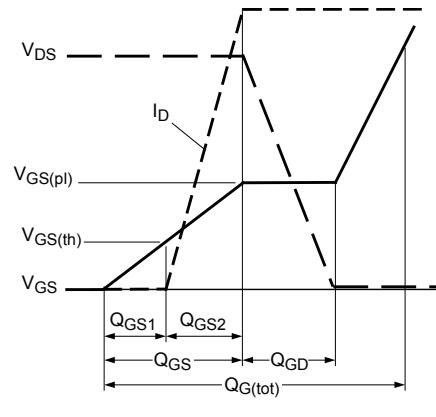


Fig. 13. Gate charge waveform definitions

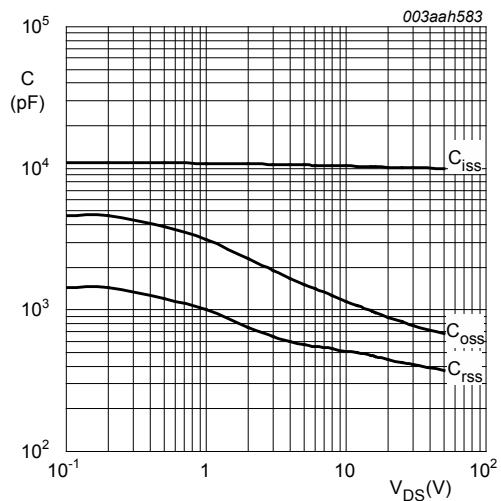


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$

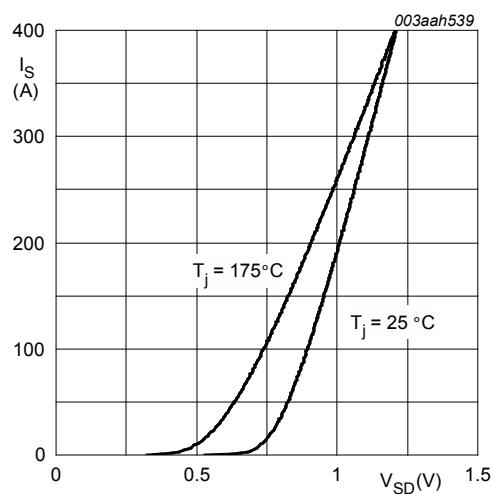
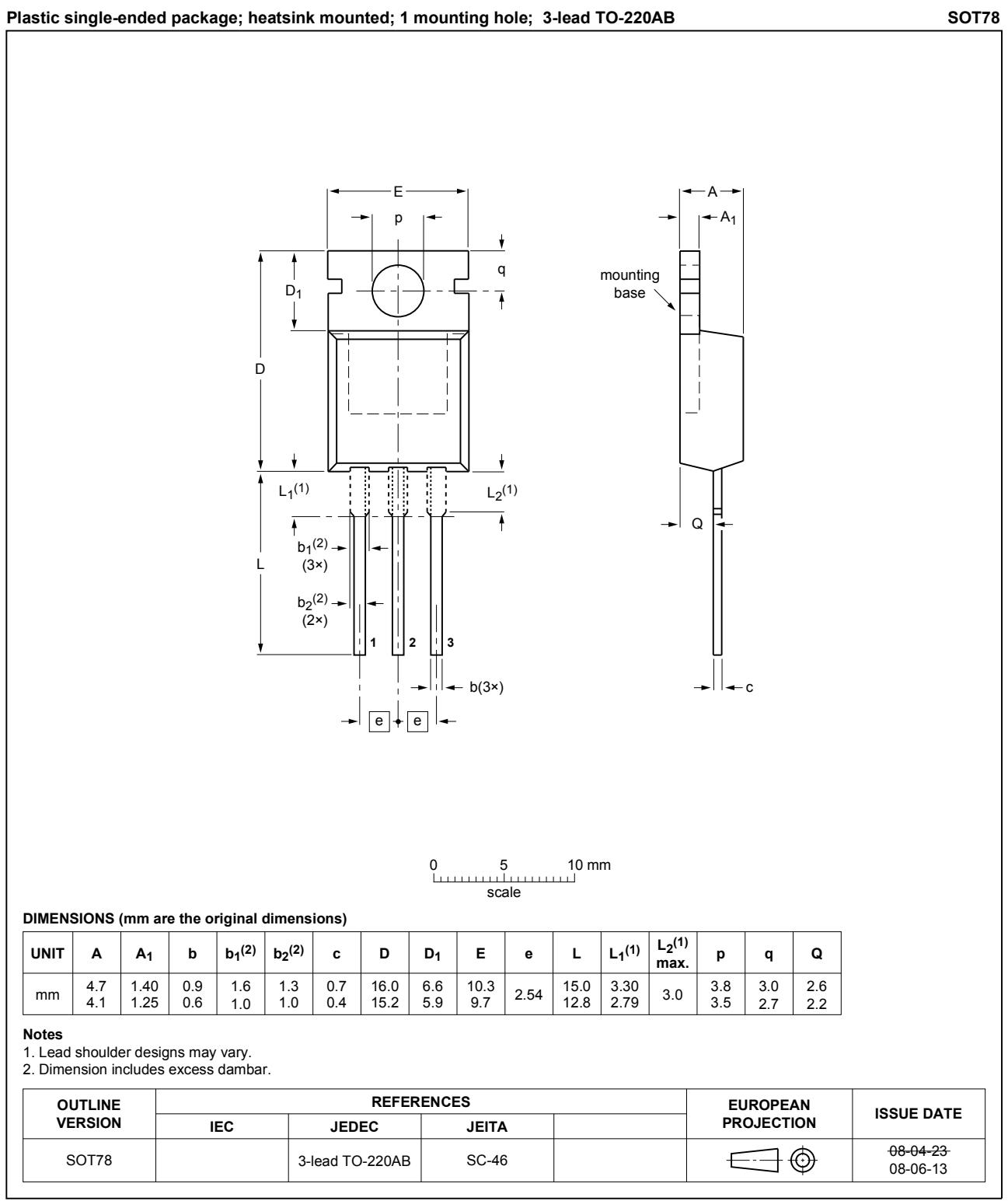


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$V_{GS} = 0V$

11. Package outline



12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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